## Medium Power Transistor (60V, 1A)

## 2SD1834

## -Features

1) Darlington connection for high $D C$ current gain (typically, DC current gain $=15000$ at $\mathrm{V}_{\mathrm{CE}}=3 \mathrm{~V}$, $\mathrm{Ic}=$ 0.5A)
2) High input impedance.

## -Circuit diagram



- External dimensions (Unit : mm)


## MPT3



- Absolute maximum ratings ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Limits | Unit |  |
| :---: | :---: | :---: | :---: | :---: |
| Collector-base voltage | Vсbo | 60 | V |  |
| Collector-emitter voltage | Vces | 60 | V | *2 |
| Emitter-base voltage | Vebo | 7 | V |  |
| Collector current | Ic | 1 | A(DC) |  |
|  |  | 2 | A(Pulse) | *1 |
| Collector power dissipation | Pc | 0.5 | W |  |
|  |  | $2 * 3$ |  |  |
| Junction temperature | Tj | 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage temperature | Tstg | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |  |

1 Single pulse $\mathrm{Pw}=100 \mathrm{~ms}$
*2 RBE=0 $\Omega$
$* 3$ Mounted on a $40 \times 40 \times t 0.7 \mathrm{~mm}$ ceramic substrate

- Electrical characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-base breakdown voltage | BVсво | 60 | - | - | V | $\mathrm{Ic}=50 \mu \mathrm{~A}$ |  |
| Collector-emitter breakdown voltage | BVceo | 60 | - | - | V | $\mathrm{Ic}=100 \mu \mathrm{~A}, \mathrm{Rbe}=0 \Omega$ |  |
| Emitter-base breakdown voltage | BVEbo | 7 | - | - | V | $\mathrm{I}_{\mathrm{E}}=50 \mu \mathrm{~A}$ |  |
| Collector cutoff current | Icbo | - | - | 1 | $\mu \mathrm{A}$ | V $\mathrm{cB}=60 \mathrm{~V}$ |  |
| Emitter cutoff current | Iebo | - | - | 1 | $\mu \mathrm{A}$ | $\mathrm{V}_{\text {Eb }}=6 \mathrm{~V}$ |  |
| DC current transfer ratio | hFE | 2000 | - | - | - | $\mathrm{V} \mathrm{ce} / \mathrm{lc}=3 \mathrm{~V} / 500 \mathrm{~mA}$ | * |
| Collector-emitter saturation voltage | V cE(sat) | - | 0.9 | 1.5 | V | $\mathrm{Ic} / \mathrm{ls}=500 \mathrm{~mA} / 500 \mu \mathrm{~A}$ |  |
| Transition frequency | ft | - | 150 | - | MHz | $\mathrm{V}_{\text {cE }}=5 \mathrm{~V}, \mathrm{IE}=-10 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}$ |  |
| Output capacitance | Cob | - | 7 | - | pF |  |  |

Transistors

## $\bullet$ Packaging specifications and $h_{\text {FE }}$

| Type | 2SD1834 |
| :---: | :---: |
| Package | MPT3 |
| hFE | $2 \mathrm{k} \sim$ |
| Marking | DE $*$ |
| Code | T100 |
| Basic ordering unit (pieces) | 1000 |
| *Denotes hFE |  |

## -Electrical characteristics curves



Fig. 1 Ground emitter output characteristics


Fig. 2 Ground emitter propagation characteristics


Fig. 3 DC current gain vs. collector current


Fig. 4 Collector-emitter saturation voltage vs. collector current


Fig. 5 Collector output capacitance vs. collector-base voltage


Fig. 6 Safe operating area

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